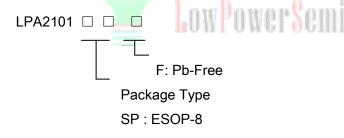


Filterless 30W Class F Mono Audio Amplifier With AGC function

General Description

The LPA2101 is a 30W, class F mono audio amplifier integrated Class AB/D optional mode and AGC function. It is capable of delivering 29watts of continuous average power to a 4Ω BTL load with less than 10% distortion (THD) from a 15V DC power supply. It offers low THD+N, allowing it to achieve high-quality Power Supply sound reproduction. The LPA2101 device is fully protected against faults with short-circuit protection and thermal protection. Faults are reported back to the processor to prevent devices form being damaged during overload conditions.

Order Information



Applications

- Mini-Micro Component, Speaker Bar, Docks
- After-Market Automotive
- Consumer Audio Applications, CRT TV
- Portable Bluetooth Speaker ✧
- Cellular and Smart mobile phone
- Square Speaker

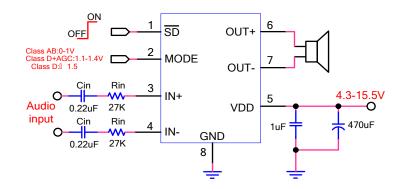
Features

- Wide voltage range: 4.3V~15.5V
- 550KHz fixed frequency switching for amplifier
- 29W Output at 10% THD with a 4Ω Load and 15V VDD for amplifier
 - 19W Output at 10% THD with a 4Ω Load and 12V VDD for amplifier
- Integrated Self-Protection Circuits Including, Under-Voltage, Over-Temperature, and Short Circuit
- High Efficient Class-D Operation: >86%
- Filterless, Low Quiescent Current and Low EMI
- Pb-Free Package

Marking Information

Device	Marking	Package	Shipping
	LPS		
LPA2101	LPA2101	ESOP-8	4000PCS/REEL
	YWX		
Y: Y is year co	ode. W: W is wee	ek code. X: X is	s series number.

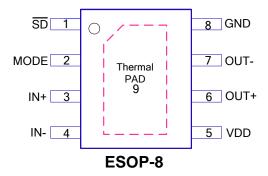
Typical Application Circuit



LPA2101-01

May.2018

Pin Configuration(TOP View)



Functional Pin Description

ESOP8 Pin Num.	Pin Name	Description
1	\overline{SD}	Shutdown pin. Active low.
2	MODE	Mode control pin. Class AB:0-1V; Class D+AGC:1.1-1.4V; Class D: >1.5V.
3	IN+	Positive input of amplifier.
4	IN-	Negative input of amplifier.
5	VDD	Voltage supply pin.
6	OUT+ Sem	Positive output of signal.
7	OUT-	Negative output of signal.
8	GND	Ground: OHIOP COM A STATE TO THE STATE OF TH
9	Thermal PAD	Power Ground.

Absolute Maximum Ratings Note 1

	Supply Voltage to GND	0.3V to 18V
	Other Pin to GND	0.3V to 9V
	Maximum Junction Temperature	150°C
	Operating Ambient Temperature Range (Ta)	
\$	Maximum Soldering Temperature (at leads, 10 sec) -	260°C

Note 1. Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Thermal Information

- Maximum Power Dissipation (ESOP-8, PD,TA=25°C) ------ 1.9W
- Thermal Resistance (ESOP-8, JA) ------ 65°C/W

ESD Susceptibility♦ HBM(Human Body Mode)

- Note 2 ______ 2KV

Note 2. The Human body model (HBM) is a 100pF capacitor discharged through a 1.5kΩ resistor into each pin. The testing is done according JEDEC.

LPA2101-01

May.2018

Note 3. Machine Model (MM) is a 200pF capacitor discharged through a 500nH inductor with no series resistor into each pin. The testing is done according JEDEC.

Electrical Characteristics

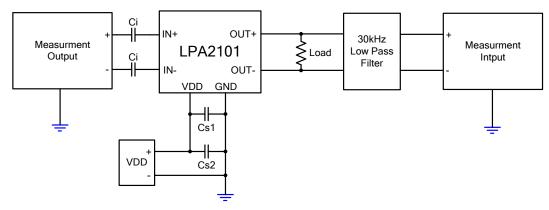
(T_A = 25°C, VDD = 12V, R_L = 4 Ω , unless otherwise noted)

Parameter	Symbol	Test Conditions	Min	Тур	Max	Units	
Supply power	VDD		4.3		15.5	V	
		TUD.N. 400/ 5 41/1- DL 40	VDD=15V		29		
		THD+N=10%, f=1KHz,RL=4Ω	VDD=12V		19		
		TUD.N. 400/ £ 41/U- DI 90	VDD=15V		16		
Output power	Po	THD+N=10%, f=1KHz,RL=8Ω	VDD=12V		10		w
Cutput power	10	THD+N=1%, f=1KHz,RL=4Ω	VDD=15V		24		•
			VDD=12V		15		
		THD+N=1%, f=1KHz,RL=8Ω	VDD=15V		13		
	111D+N=176, I=1K112,KL=012		VDD=12V		8.5		
Power supply ripple PSE	PSRR	INPUT ac-grounded with	f=100HZ		-73		dB
rejection	ection CIN=0.47uF, VDD=12V		f=1KHz	FE	-70		GD_
Signal-to-noise ratio	SNR	VDD=12V,P _{OUT} =12W,R _L =4Ω	f=1KHz		95		dB
Output integrated noise	Vn	22 Hz to 20kHz, filter,THD=1%,RL=4 Ω	A-weighted		130		μV
Eifficency	η	$R_L=4\Omega, P_O=10W$	f=1KHz		86		%
Quiescent current	ΙQ	VDD=12V	No load		25		mA
Shutdown current	I _{SD}	VDD=12V,V _{SD} =0			12		uA
SD High level input voltage	VIH	VDD=12V		1			V
SD Low level input voltage	VIL	VDD=12V				0.6	V
Offset output voltage	Vos	VDD=12V, V _{SD} =0V		5		mV	
fosc Oscillator frequency	fsw			550		KHz	
start-up time	Ton	SD from low to high			180		ms
Thermal shutdown	ОТР	Threshold			155		°C
Thermal shutdown Hysteresis	ОТРН	Hysteresis			135		$^{\circ}$

LPA2101-01

May.2018

Test setup for graphs

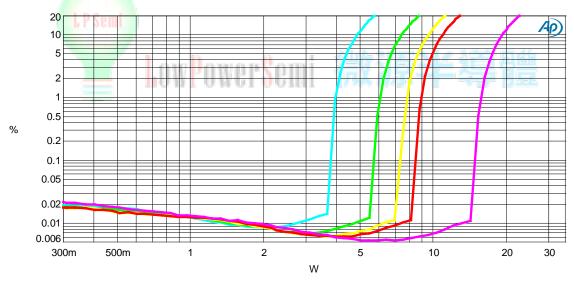


- 1. Ci was shorted for any common-mode input voltage measurement. All other measurements were taken with Ci = 1µF (unless otherwise noted).
- 2. Cs1 = 0.1 μ F is placed very close to the device. The optional Cs2 = 10 μ F is used for datasheet graphs.
- 3. The 30 kHz low-pass filter is required even if the analyzer has an internal low-pass filter. An RC low-pass filter (1 k Ω , 4700pF) is used on each output for the data sheet graphs.

Typical Operating Characteristic For Amplifier

PO VS THD

Audio Precision

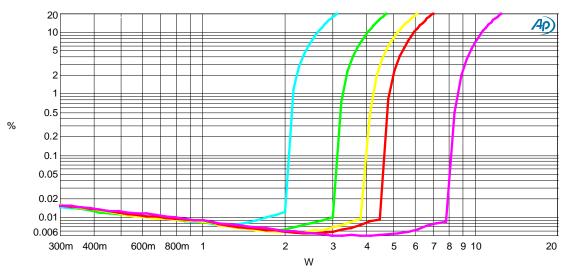


Sweep	Trace	Color	Line Style	Thick	Data	Axis	Comment
1	1	Cyan	Solid	3	Analyzer.THD+N Ratio A	Left	VDD=6V,RL=4ohm
2	1	Green	Solid	3	Analyzer.THD+N Ratio A	Left	VDD=7.4V,RL=4ohm
3	1	Yellow	Solid	3	Analyzer.THD+N Ratio A	Left	VDD=8.4V,RL=4ohm
4	1	Red	Solid	3	Analyzer.THD+N Ratio A	Left	VDD=9V,RL=4ohm
5	1	Magenta	Solid	3	Analyzer.THD+N Ratio A	Left	VDD=12V,RL=4ohm

PO VS THD@4ohm.ats2

LPA2101–01 May.2018 Email: marketing@lowpowersemi.com www.lowpowersemi.com Page 4 of 10

Audio Precision

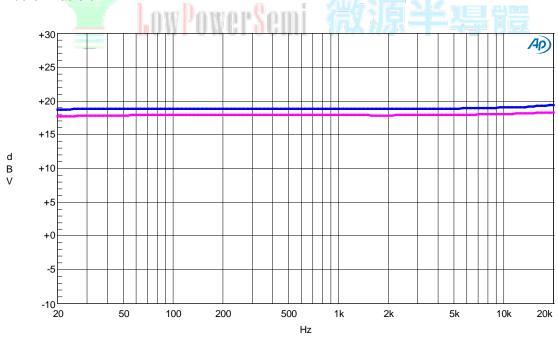


Trace	Color	Line Style	Thick	Data	Axis	Comment
1	Cyan	Solid	3	•		•
1	Yellow	Solid	3	Analyzer.THD+N Ratio A	Left	VDD=8.4V,RL=8ohm
1 1	Red Magenta	Solid Solid	3	,		
	1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1	1 Cyan 1 Green 1 Yellow	1 Cyan Solid 1 Green Solid 1 Yellow Solid 1 Red Solid	1 Cyan Solid 3 1 Green Solid 3 1 Yellow Solid 3 1 Red Solid 3	1 Cyan Solid 3 Analyzer.THD+N Ratio A 1 Green Solid 3 Analyzer.THD+N Ratio A 1 Yellow Solid 3 Analyzer.THD+N Ratio A 1 Red Solid 3 Analyzer.THD+N Ratio A	1 Cyan Solid 3 Analyzer.THD+N Ratio A Left 1 Green Solid 3 Analyzer.THD+N Ratio A Left 1 Yellow Solid 3 Analyzer.THD+N Ratio A Left 1 Red Solid 3 Analyzer.THD+N Ratio A Left

PO VS THD@8ohm.ats2

Frequency response

Audio Precision



Sweep	Trace	Color	Line Style	Thick	Data	Axis	Comment
5 6	1 1	Magenta Blue	Solid Solid	3	•		VDD=12V,RL=40hm,THD=1% VDD=12V,RL=40hm,THD=10%

LPA2101-01

May.2018

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Applications Information

Maximum Gain

The LPA2101 has two internal amplifier stages. The first stage's gain is externally configurable, while the second stage's is internally fixed. The closed-loop gain of the first stage is set by selecting the ratio of Rf to Ri while the second stage's gain is fixed at 2x. The output of amplifier 1 serves as the input to amplifier 2, thus the two amplifiers produce signals identical in magnitude, but different in phase by 180°. Consequently, the differential gain for the IC is

 $A_V = 20 \log [2 Rf/(Ri+6)]$

Class AB: Rf= 100 k $\Omega \pm 10\%$ Class D: Rf= 250 k $\Omega \pm 10\%$

Shutdown operation

L P Cem

In order to reduce power consumption while not in use, the LPA2101 contains shutdown circuitry to turn off the amplifier's bias circuitry. This shutdown feature turns the amplifier off when logic low is applied to the SD pin.

Power supply decoupling

Power supply leads. For higher frequency transients, spikes, or digital hash on the line, a good low equivalent-series-resistance (ESR) ceramic capacitor, typically 1.0µF, works best, placing it as close as possible to the device VDD terminal. For filtering lower- frequency noise signals, a large capacitor of 20µF (ceramic) and a capacitor of 220uF(electrolytic) are recommended, placing them near the audio power amplifier.

The LPA2101 has short circuit protection circuitry on the outputs to prevent damage to the device when output-to-output or output-to-GND short occurs. When a short circuit is detected on the outputs, the outputs are disabled immediately. If the short was removed, the device activates again.

Input Capacitor (Ci)

Ci for signal input. Large input capacitors are both expensive and space hungry for portable designs. Clearly, a certain sized capacitor is needed to couple in low frequencies without severe attenuation. But in many cases the speakers used in portable systems, whether internal or external, have little ability to reproduce signals below 100Hz to 150Hz. In the typical application, an input capacitor Ci is required to allow the amplifier to bias the input signal to the proper dc level for optimum operation. Thus, using a large input capacitor may not increase actual system performance. In this case, input capacitor (Ci) and input resistance (Ri) of the amplifier form a high-pass filter with the corner frequency determined by equation below,

$$f_C = \frac{1}{2\pi RiCi}$$

Over Temperature Protection

Thermal protection on the LPA2101 prevents the device from damage when the internal die temperature exceeds 155°C. There is a ± 15°C tolerance on this trip point from device to device. Once the die temperature exceeds the thermal set point, the device outputs are disabled. This is not a latched fault. The thermal fault is cleared once the

Short Circuit Protection (SCP)

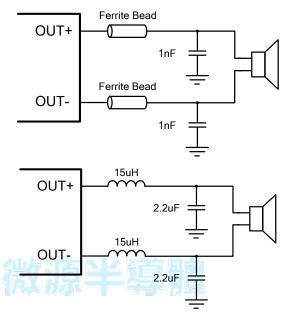
LPA2101–01 May.2018 Email: marketing@lowpowersemi.com www.lowpowersemi.com Page 6 of 10

temperature of the die is reduced by 20°C. This large hysteresis will prevent motor boating sound well and the device begins normal operation at this point without external system intervention.

How to reduce EMI

A simple solution is to put an additional capacitor at power supply terminal for power line. The traces from amplifier to speakers should design as short as we can. The LPA2101 has been tested with a simple ferrite bead filter for a variety of applications. The LPA2101 EVM passes FCC class-B specifications under these conditions using twisted speaker wires. The size and type of ferrite bead can be selected to meet application requirements. Also, the filter capacitor can be increased if necessary with some impact on efficiency. There may be a few circuit instances where it is necessary to add a complete LC reconstruction filter. These circumstances might occur if there are nearby circuits which are sensitive to noise. In these cases a classic second order Butterworth filter similar to those shown in the figures below can be used.

Some systems have little power supply decoupling from the AC line but are also subject to line conducted interference (LCI) regulations. These include systems powered by "wall warts" and "power bricks." In these cases, LC reconstruction filters can be the lowest cost means to pass LCI tests. Common mode chokes using low frequency ferrite material can also be effective at preventing line conducted interference.



LPA2101-01 May.:

May.2018



PCB Layout notices

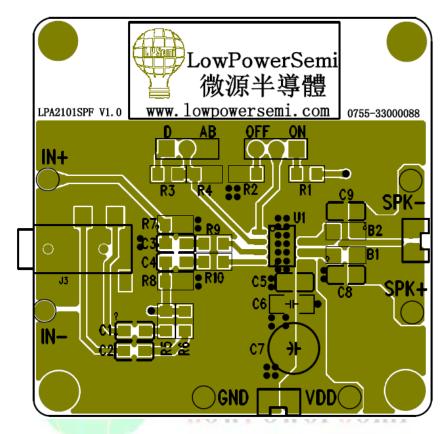
- 1, In the path of the power supply, plus a 1uF and a 10uF to ground high-frequency filter capacitor. These caps can be connected to the thermal pad directly for an excellent ground connection. Consider adding a small, good quality low ESR ceramic capacitor may achieve better sound effects.
- 2, Large (470 μ F or greater) bulk power supply decoupling capacitors should be placed near the LPA2101 on the VDD supplies. Local, high-frequency bypass capacitors should be placed as close to the VDD pins as possible.
- 3, The power line, ground line and filter capacitor and bypass capacitors as close to the chip's pins, remember not to put the capacitor on the back of the board, through tiny holes through the jumper even over. Keep the current loop from each of the outputs through the ferrite bead and the small filter cap and back to GND as small and tight as possible. The size of this current loop determines its effectiveness as an antenna.
- 4, Power, ground, and a large current line must try to be wide enough, if you want to add vias, the number of through-holes must be at least 6. The thermal pad must be soldered to the PCB for proper thermal performance and optimal reliability.
- 5, GND and VDD should be put independently, high-power signals to avoid interference.
- 6, If you want to pursue as large as the effect of power, a large selection of speakers or sound chamber with low resistance (such as 3.6Ω) speakers, or added to improve the supply voltage.
- 7, Including the line between large current cell and chip, the inductor should be as close and short as possible to chip for a high performance. Adding a coil to this pin would be helpful for EMI certification. If there is a high standards needed in LPA2101 application, we could add a coil and capacitor between chip and speaker constituting a LC filter which coil would be 100MHz, 600Ω and its DCI beyond 4A placing as close as possible to chip, the capacitor should be 1nF connecting the GND.
- 8, The position under the amplifier chip on the board must be added vents and large areas of exposed copper and tin to enhance heat dissipation.
- 9, In case of fixed gain and meeting demand, it should make CIN small as possible as we can because it constitute a high through filter with Rin which cutoff frequency is 1/2*3.414*Cin*Rin. A high capacitance cap could make POP worse.

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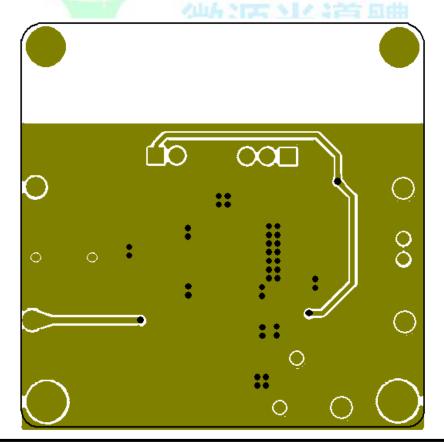
May.2018



PCB LAYOUT TOP VIEW:



BOTTOM VIEW:

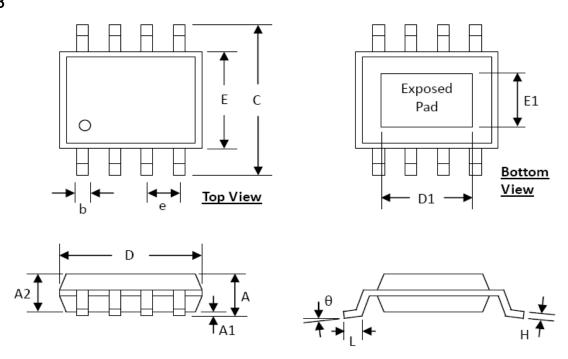


May.2018 LPA2101-01



Packaging Information

ESOP-8



SYMBOLS	DIMENSI	ON (MM)	DIMENSIO	ON (INCH)	
STIVIBOLS	MIN	MAX	MIN	MAX	
А	1.30	1.70	0.051	0.067	
A1	0.00	0.15	0.000	0.006	
A2	1.25	1.52	0.049	0.060	
b	0.33	0.51	0.013	0.020	
С	5.80	6.20	0.228	0.244	
D	4.80	5.00	0.189	0.197	
D1	3.15	3.45	0.124	0.136	
E	3.80	4.00	0.150	0.157	
E1	2.26	2.56	0.089	0.101	
е	1.27	BSC	0.050 BSC		
Н	0.19	0.25	0.0075	0.0098	
L	0.41	1.27	0.016	0.050	
θ	0°	8°	0°	8°	

LPA2101-01 May.2018 Email: marketing@lowpowersemi.com www.lowpowersemi.com Page 10 of 1

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